

### April 2015

# FGH60N60UFDTU\_F085 600V, 60A Field Stop IGBT

### Features

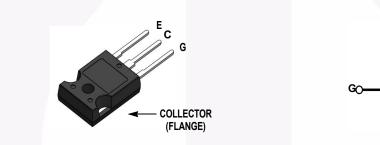
- High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> = 1.8 V @ I<sub>C</sub> = 60 A
- High Input Impedance
- Fast Switching
- RoHS Compliant
- Qualified to Automotive Requirements of AEC-Q101

## Applications

- · Automotive chargers, Converters, High Voltage Auxiliaries
- Inverters, PFC, UPS

## **General Description**

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.



## Absolute Maximum Ratings

Symbol	Descriptio	n	Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		600	V
V	Gate to Emitter Voltage	±20	V	
V <sub>GES</sub>	Transient Gate-to-Emitter Voltage	±30	v	
	Collector Current	@ T <sub>C</sub> = 25°C	120	A
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	60	A
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	180	A
	Maximum Power Dissipation	@ T <sub>C</sub> = 25 <sup>o</sup> C	298	W
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	119	W
TJ	Operating Junction Temperature	-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second	300	°C	

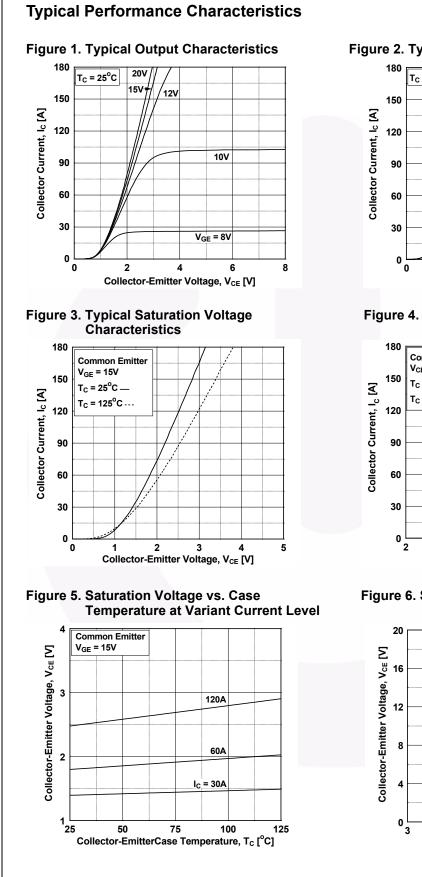
Notes: 1: Repetitive test , Pulse width limited by max. junction temperature

### **Thermal Characteristics**

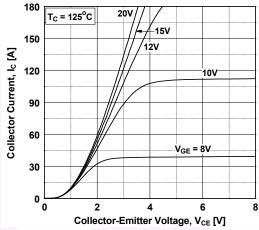
Symbol	Parameter	Тур.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	0.33	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	1.1	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	40	°C/W

Part Number Top Mark Pacl		kage Packing Method		Reel Size	Tape V	Vidth	Quantity 30		
FGH60N60	GH60N60UFDTU_F085 FGH60N60UFD TO		-247 Tube		N/A	N/A			
Electric	al Charac	teristics of t	he IO	ЗВТ	T <sub>C</sub> = 25°C unless otherwise not	ed			
Symbol		Parameter			Test Conditions	Min.	Тур.	Мах	. Unit
Off Charac	teristics								
BV <sub>CES</sub>	Collector to Er	mitter Breakdown V	oltage	V <sub>GF</sub> =	: 0 V, I <sub>C</sub> = 250 μA	600	-	-	V
$\Delta BV_{CES}$ / $\Delta T_J$		Coefficient of Break			= 0 V, I <sub>C</sub> = 250 μA	-	0.67	-	V/ºC
I <sub>CES</sub>	Collector Cut-	Off Current		$V_{CE} = V_{CES}, V_{GE} = 0 V$ $V_{GE} = V_{GES}, V_{CE} = 0 V$		-	-	250	μA
I <sub>GES</sub>	G-E Leakage	Current				-	-	±400	nA
On Charac	teristics						I		
V <sub>GE(th)</sub>	G-E Threshold	d Voltage	-	lc = 2	50 μΑ, V <sub>CE</sub> = V <sub>GE</sub>	4.0	5.0	6.5	V
		a ronago		-	0 A, V <sub>GE</sub> = 15 V	-	1.8	2.9	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage		I <sub>C</sub> = 6	0 A, V <sub>GE</sub> = 15 V, 125°C	-	2.1	-	V	
Dvnamic C	haracteristics			1					
C <sub>ies</sub> Input Capacitance				-	2540	-	pF		
C <sub>oes</sub>	Output Capac		_	$V_{CE} = 30 V, V_{GE} = 0 V,$		-	330	-	pF
C <sub>res</sub>		sfer Capacitance		f = 1 MHz		-	110	-	pF
Switching	Characteristic	s		1		I			
t <sub>d(on)</sub>	Turn-On Delay Time				-	29	-	ns	
t <sub>r</sub>	Rise Time			$V_{CC}$ = 400 V, I <sub>C</sub> = 60 A, R <sub>G</sub> = 5 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 25°C		-	60	-	ns
t <sub>d(off)</sub>	Turn-Off Dela	y Time				-	138	-	ns
t <sub>f</sub>	Fall Time	<u>.</u>				-	28	80	ns
E <sub>on</sub>	Turn-On Swite	ching Loss				-	2.47	-	mJ
E <sub>off</sub>	Turn-Off Swite	ching Loss				-	0.81	-	mJ
E <sub>ts</sub>	Total Switchin	g Loss		1		-	3.28	-	mJ
t <sub>d(on)</sub>	Turn-On Dela					-	28	-	ns
t <sub>r</sub>	Rise Time			ł		-	55	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	y Time		V <sub>CC</sub> = 400 V, I <sub>C</sub> = 60 A,		-	147	-	ns
t <sub>f</sub>	Fall Time	· · · · · · · · · · · · · · · · · · ·		$R_G = 1$	5 Ω, V <sub>GE</sub> = 15 V,	-	71	-	ns
E <sub>on</sub>	Turn-On Swite			Inductive Load, T <sub>C</sub> = 125 <sup>o</sup> C		-	3.01	-	mJ
E <sub>off</sub>	Turn-Off Swite	ching Loss				-	1.21	-	mJ
E <sub>ts</sub>	Total Switchin	g Loss				-	4.22	-	mJ
Qg	Total Gate Ch	arge				-	192	-	nC
Q <sub>ge</sub>	Gate to Emitte	-		$V_{CE} =$	400 V, I <sub>C</sub> = 60 A,	-	24	-	nC
Q <sub>gc</sub>	Gate to Collec	-		V <sub>GE</sub> =	15 V	-	102	-	nC

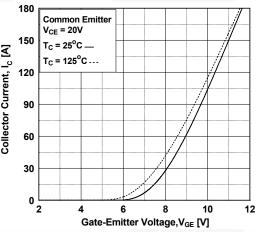
Symbol	Parameter	Test Condition	าร	Min.	Тур.	Max	Units
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25°C	-	1.70	2.6	V
* FM			T <sub>C</sub> = 125 <sup>o</sup> C	-	1.54	-	
t	Diode Reverse Recovery Time		T <sub>C</sub> = 25°C	-	76	-	ns
۲r		I <sub>F</sub> = 30 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 125°C	-	242	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge	η <sub>F</sub> = 30 Α, αιείαι = 200 Αίμο	T <sub>C</sub> = 25°C	-	208	-	nC
~!!			T <sub>C</sub> = 125 <sup>o</sup> C	-	1162	-	

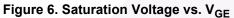


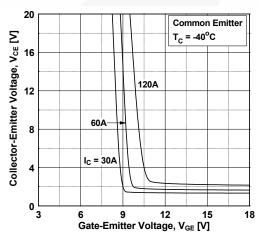
### Figure 2. Typical Output Characteristics



**Figure 4. Transfer Characteristics** 

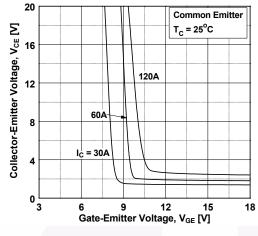




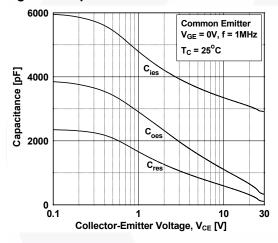


## **Typical Performance Characteristics**





**Figure 9. Capacitance Characteristics** 





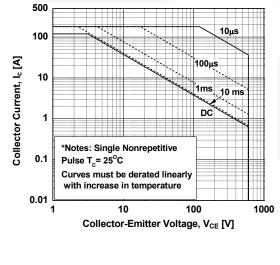


Figure 8. Saturation Voltage vs. V<sub>GE</sub>

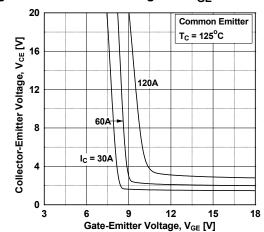


Figure 10. Gate charge Characteristics

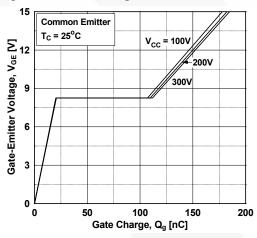
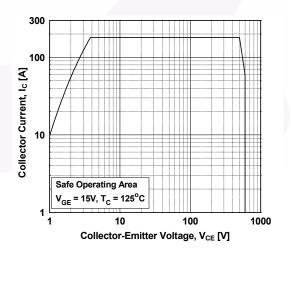
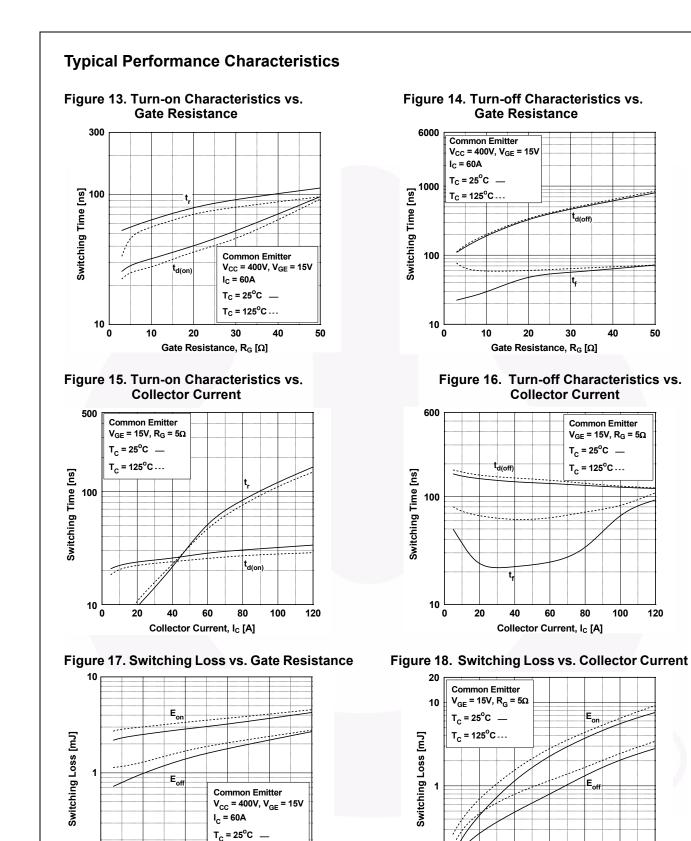


Figure 12. Turn off Switching SOA







## FGH60N60UFDTU\_F085 Rev.1.0

Gate Resistance, R<sub>G</sub> [Ω]

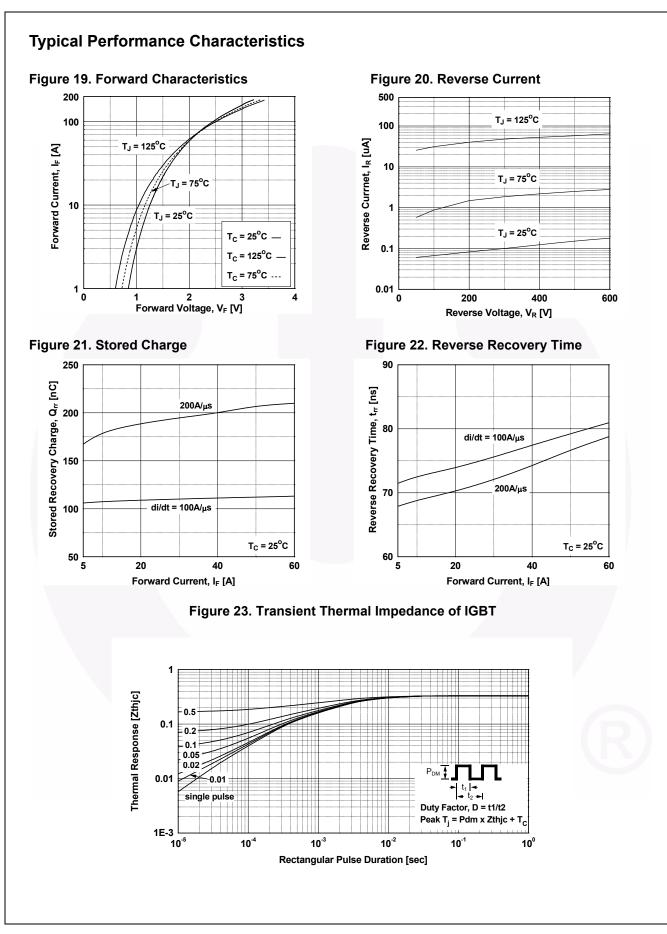
0.1

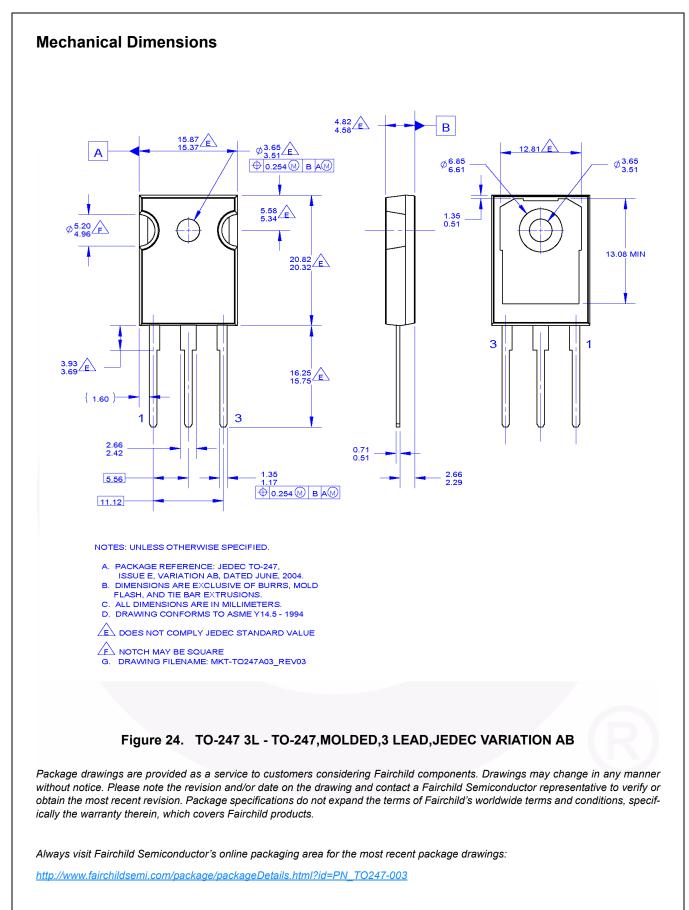
T<sub>C</sub> = 125<sup>o</sup>C ...

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0.1

Collector Current, Ic [A]







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